









# PRODUCT DATASHEET

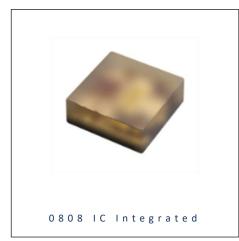


- ► CHIP SMD with IC
- ▶ 0808 (2020) IC 0.75t
- ► Red/Green/Blue

NOM67S14IC







# 0808 IC-Integrated Compliant



AEC-Q100



**AEC-Q102** 

#### **FEATURES:**

Package: CHIP EIA STD Package 6 Pins with Integrated IC

Output Current: 20mA/Channel

LED Voltage: 4.5~5.5V

Luminous Intensity (typ.): 280/850/150mcd\*

Colour: Red/Green/Blue

Dominant Wavelength (typ.): 633/527/457nm

Viewing Angle: 120°

**Materials:** 

Resin: Epoxy (Water Clear)

Operating Temperature: -40~+85°C

Storage Temperature: -40~+85°C

- IC Feature: Serial data transmission signal by DATA CLK two lines. Supports sleep/wake-up mode. In sleep mode, the LED's current was lower than 5µA.
- Pixel: One pixel contains R, G, and B colour that each can achieve 256 level brightness grayscales, which forms 16,777,216 combination colours.
- **Soldering methods:** IR reflow soldering
- MSL Level: acc. to JEDEC Level 3
- Packing: 8mm tape with max.4000pcs/reel, ø180mm (7")

\* in order of Red/Green/Blue

#### **APPLICATIONS:**

- Telecommunication
- Status Indicator
- Home Appliance
- **Decoration Lighting**
- Full Colour LED Strip
- **Gaming Device**

Support sleep/wake up mode. In sleep mode the LED's current was lower than 5µA



### **CHARACTERISTICS:**

# Absolute Maximum Characteristics (Ta=25°C)

Parameter	Symbol	Ratings	Unit
The Max. LED Output Current	Іомах	20/Channel	mA
IC Power Supply Voltage	V <sub>DD</sub>	< 6.5	V
LED Voltage	V <sub>LED</sub>	4.5~5.5	V
Power Dissipation	PD	< 400	mW
Rate of Data Signal	F <sub>CLK</sub>	15	MHz
Operating Temperature	T <sub>OPR</sub>	-40~+85	°C
Storage Temperature	T <sub>STG</sub>	-40~+85	°C
Electrostatic Discharge (HBM)	ESD	6000	V
Soldering Temperature	T <sub>SD</sub>	260 for 10s max.	°C

# Electrical & Optical Characteristics (Ta=25°C, V<sub>DD</sub>=5V)

Parameter		Cumbal		Values	Lloit	Test	
		Symbol	Min.	Тур.	Max.	Unit	Condition
LED Voltage		V <sub>LED</sub>	4.5		5.5	V	
	R		220	280	350		
Luminous Intensity	G	lv	700	850	1050	mcd	V <sub>DD</sub> =5V
	В		120	150	200		
	R		630		636		
Dominant Wavelength	G	$\lambda_{\sf d}$	524		529	nm	V <sub>DD</sub> =5V
	В		455		460		
Viewing Angle		2θ <sub>1/2</sub>		120		deg	V <sub>DD</sub> =5V

- 1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.
- 2.  $2\theta_{1/2}$  is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
- 3. The dominant wavelength,  $\lambda_d$  is derived from CIE chromaticity diagram and represents the single wavelength which defines the color of the device. Peak emission wavelength tolerance is  $\pm 1$ nm.



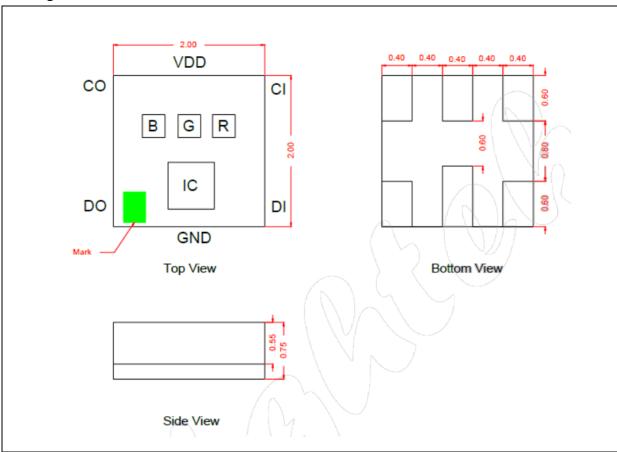
# Electrical Characteristics (Ta=25°C, V<sub>DD</sub>=5V)

Parameter	Symbol		Values	Unit	Test	
rarameter	Зуппоот	Min.	Тур.	Max.	Ullit	Condition
Supply Voltage	$V_{DD}$	4.5	5.0	5.5	V	
Input High Voltage	V <sub>IH</sub>	2.7		V <sub>DD</sub> +0.4	V	
Input Low Voltage	VIL	-0.4		1.0	V	
Clock High Level Width	T <sub>CLKH</sub>	30			ns	
Clock Low Level Width	T <sub>CLKL</sub>	30			ns	
Data Setup Time	T <sub>SETUP</sub>	10			ns	
Data Hold Time	T <sub>HOLD</sub>	5			ns	
Working Current (IC)	I <sub>DD</sub>			2	mA	I <sub>out</sub> ="OFF"
Static Current	I <sub>Sleep</sub>			5	μΑ	Sleep Mode



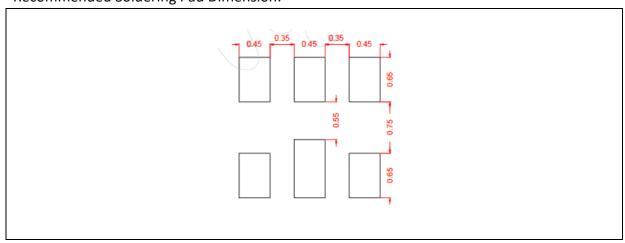
## **OUTLINE DIMENSION:**

# Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm, unless otherwise noted.

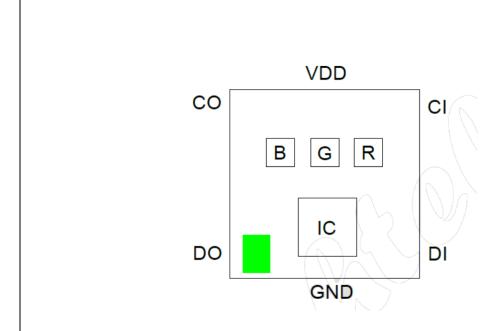
## **Recommended Soldering Pad Dimension:**



- 1. Dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm with angle tolerance ±0.5°.



# **PIN CONFIGURATION:**



No.	Symbol	Function Description
1	СО	Clock Output
2	VDD	Supply Voltage
3	CI	Clock Input
4	DO	Data Output
5	GND	Ground
6	DI	Data Input

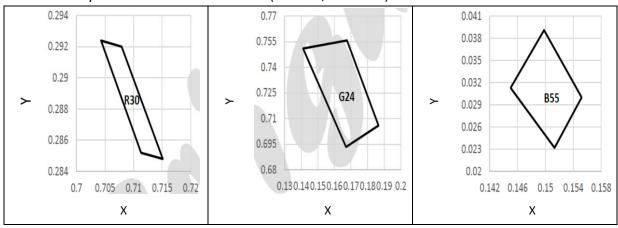


## **BINNING GROUPS:**

# Luminous Intensity Classifications (V<sub>DD</sub>=5V, I<sub>F</sub>=20mA):

Co	de	Min.	Max.	Unit
Pad	1	220	280	med
Red	2	280	350	mcd
Green	1	700	850	mcd
	2	850	1050	
Divo	1	120	150	m ad
Blue	2	150	200	mcd

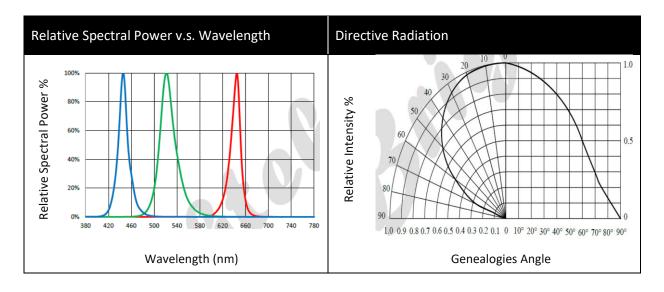
# Chromaticity Coordinate Classifications (V<sub>DD</sub>=5V, I<sub>F</sub>=20mA):

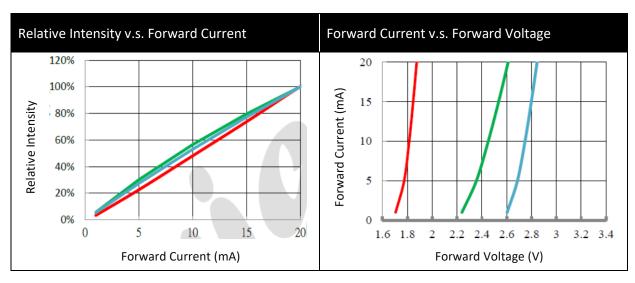


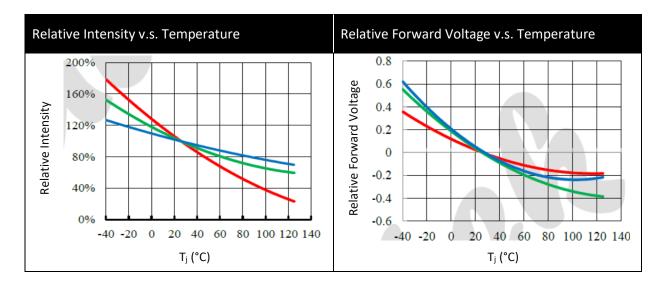
	-	l	2	2	3	3	4	1
	Х	Υ	Х	Υ	Х	Υ	Х	Υ
R30	0.7043	0.2924	0.7079	0.2920	0.7151	0.2848	0.7113	0.2852
G24	0.1676	0.7558	0.1411	0.7510	0.1670	0.6934	0.1866	0.7059
B55	0.1450	0.0313	0.1513	0.0232	0.1552	0.0300	0.1498	0.0391



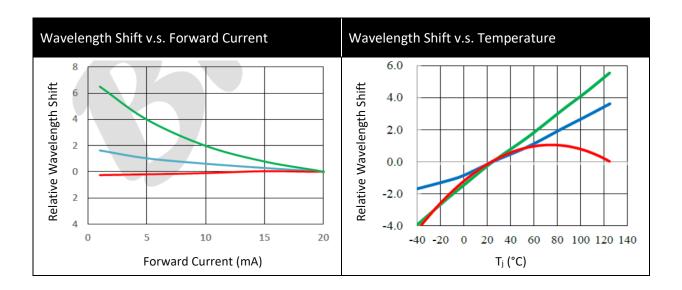
# **ELECTRO-OPTICAL CHARACTERISTICS (Full PWM):**







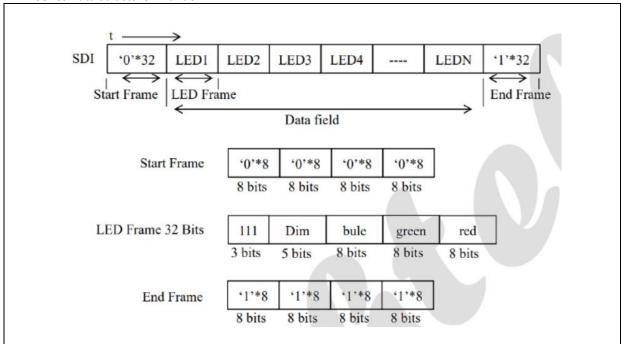






# **Function Description:**

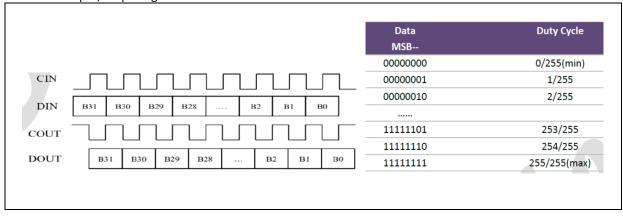
1. Series Data Structure – Tandem N-LED:



2. Dim 5-Bit (level 32) brightness adjustment (simultaneous control of OUTR\OUTG\OUTB three port current):

	Data	Driving Current
MSI	B <b>←→</b> LSB	
	00000	0/31
	00001	1/31
	00010	2/31
	11110	30/31
	11111	31/31(max)

3. PWM input/output signals relations:

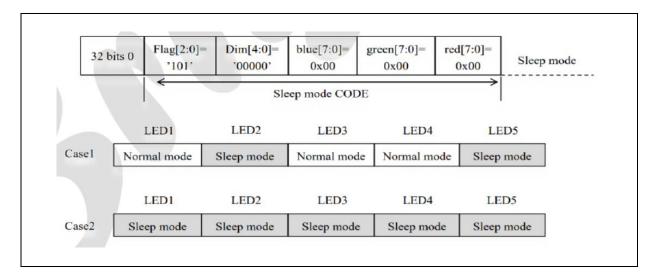




#### 4. Sleep and power saving mode:

LED supports the sleep/wake-up modes for power-saving purpose. After the IC receives 24-bitS 0's BGR data (that is B[7:0]=8h00, G[7:0]=8h00, R[7:0]=8h00), in the meantime, both of the data in 3-bits FLAG and 5-bits DIMMING is 8h'A0' (that is FLAG[2:0] =3b101 and DIMMING [4:0] =5b00000), the IC will enter sleep mode, its current is about  $1\mu$ A.

The IC will wake up from sleep mode once receiving the new data with the data of FLAG[2:0], DIMMING[4:0] is not 8h"A0"; after wake-up, all sleeping circuits in IC return to normal working mode within1ms. Since it takes 1ms for a sleeping IC returning to normal function mode, it is recommended for a host to wait for 1ms to send display data and command after issuing a wake-up command.

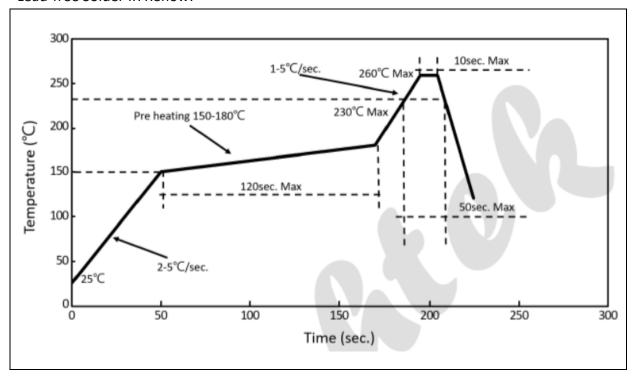


In case 1, while lamp 2 is under sleep mode, in the following data transfer process, the state of lamp 2 will be not changed as long as the 32-bits data for lamp 2 is received with data of FLAG[2:0] and DIMMING[4:0] being 8h"A0". It means lamp 2 will keep in sleep mode as well. In the situation, lamp 2 can pass through the remaining data to lamp 3 (32-bits) to change the display data of lamp 3. In other words, the sleeping chip is able to pass the data to the next chips.



### **ECOMMENDED SOLDERING PROFILE:**

### Lead-free Solder IR Reflow:



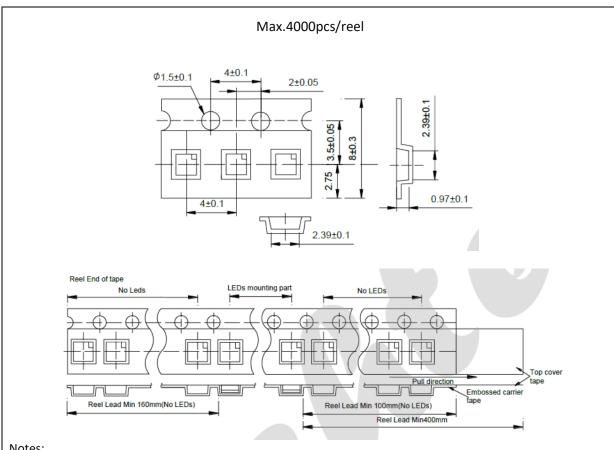
#### Note:

- 1. We recommend the reflow temperature 240°C (±5°C). The maximum soldering temperature should be limited to 260°C.
- 2. Maxima reflow soldering: 3 times.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



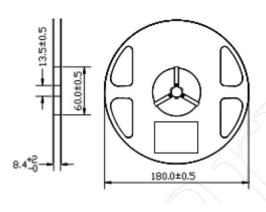
## **PACKING SPECIFICATION:**

#### Reel Dimension:



#### Notes:

- 1. Empty component pockets are sealed with top cover tape.
- 2. The max loss number of SMD is 2pcs.
- 3. The cathode is oriented towards the tape sprocket hole in accordance with ANSI/EIA RS-481 specifications.
- 4. The remainder packing in multiples of 500pcs.





#### **PRECAUTIONS OF USE:**

#### Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within 24 hours. Otherwise, they should be kept in a damp-proof box with descanting agent stored at R.H.<20% and apply baking before use.

#### Over-Current Proof:

Must apply resistors for protection otherwise slight voltage shift will cause big current change and burnout will happen.

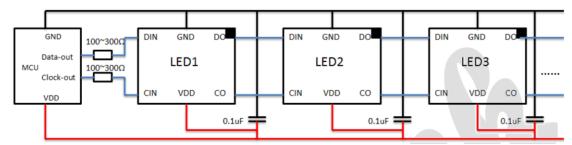
#### Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

60±3°C x 6hrs and <5%RH, taped / reel package.</li>

It's normal to see slight color fading of carrier (light yellow) after baking in process.

#### **Testing Circuit:**



When the first LED is connected to the MCU, a resistance R is needed in series between its signal input line and the MCU. The size of R depends on the number of cascade beads. The more cascades, the smaller resistance R is used. It is generally recommended that the value be between 100-1K. Usually the recommended value is around 300 R. In order to make the LEDs work more stably, a parallel capacitor is needed between VDD and GND of each.

### Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

#### ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.



# **REVISION RECORD:**

Version	Date	Summary of Revision
A1.0	28/11/2022	Datasheet set-up.
A1.1	11/08/2024	Update automotive qualification.
A1.2	13/09/2024	Add product photos.